# NSN 5961-01-352-1798

Transistor - Page 1 of 1



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## Internal Configuration:

Field effect

Semiconductor Material:

Gallium arsenide

## Voltage Rating In Volts Per Characteristic:

-6.0 gate to source voltage

### **Current Rating Per Characteristic:**

100.00 milliamperes drain current

### **Power Rating Per Characteristic:**

400.0 milliwatts total power dissipation

Shelf Life:

N/a

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Unit Of Measure:

Demilitarization:

No

Fiig:

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